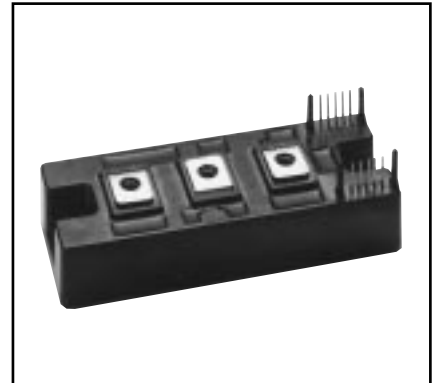
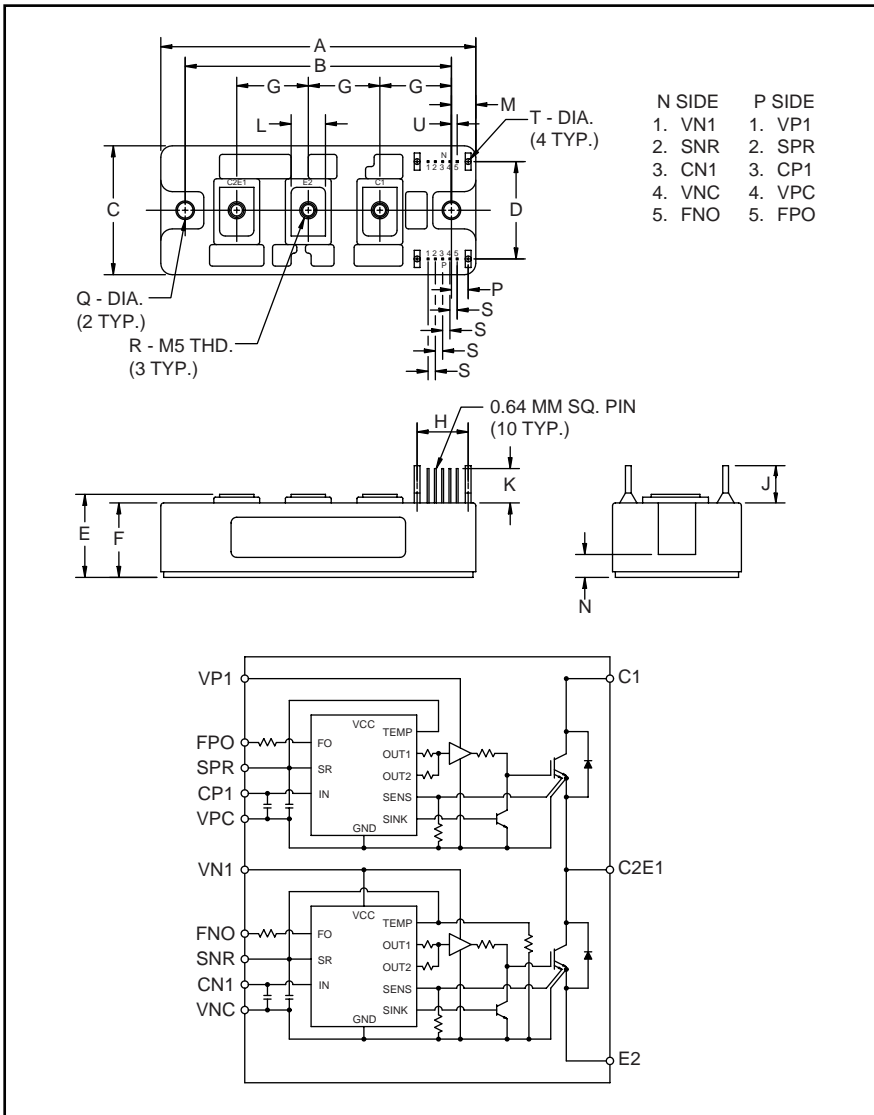


PM100DSA120

FLAT-BASE TYPE
INSULATED PACKAGE



Description:

Mitsubishi Intelligent Power Modules are isolated base modules designed for power switching applications operating at frequencies to 20kHz. Built-in control circuits provide optimum gate drive and protection for the IGBT and free-wheel diode power devices.

Features:

- Complete Output Power Circuit
- Gate Drive Circuit
- Protection Logic
 - Short Circuit
 - Over Current
 - Over Temperature
 - Under Voltage

Applications:

- Inverters
- UPS
- Motion/Servo Control
- Power Supplies

Ordering Information:

Example: Select the complete part number from the table below -i.e. PM100DSA120 is a 1200V, 100 Ampere Intelligent Power Module.

| Type | Current Rating Amperes | V _{CEs} Volts (x 10) |
|------|---------------------------|----------------------------------|
| PM | 100 | 120 |

Outline Drawing and Circuit Diagram

| Dimensions | Inches | Millimeters |
|------------|------------------|--------------|
| A | 4.33 | 110.0 |
| B | 3.66±0.010 | 93.0±0.25 |
| C | 1.77 | 45.0 |
| D | 1.34 | 34.0 |
| E | 1.14 +0.04/-0.02 | 29.0 +1/-0.5 |
| F | 1.02 | 26.0 |
| G | 0.98 | 25.0 |
| H | 0.702 | 17.84 |
| J | 0.55 | 14.0 |
| K | 0.51 | 13.0 |

| Dimensions | Inches | Millimeters |
|------------|-----------|-------------|
| L | 0.47 | 12.0 |
| M | 0.33 | 8.5 |
| N | 0.28 | 7.0 |
| P | 0.230 | 5.84 |
| Q | 0.22 Dia. | Dia. 5.5 |
| R | M5 Metric | M5 |
| S | 0.100 | 2.54 |
| T | 0.08 Dia. | Dia. 2.0 |
| U | 0.08 | 2.0 |

PM100DSA120

FLAT-BASE TYPE
INSULATED PACKAGE

Absolute Maximum Ratings, $T_j = 25^\circ\text{C}$ unless otherwise specified

| | Symbol | Ratings | Units |
|--|------------------------|------------|---------------------------|
| Power Device Junction Temperature | T_j | -20 to 150 | $^\circ\text{C}$ |
| Storage Temperature | T_{stg} | -40 to 125 | $^\circ\text{C}$ |
| Case Operating Temperature | T_c | -20 to 100 | $^\circ\text{C}$ |
| Mounting Torque, M5 Mounting Screws | — | 2.5~3.5 | $\text{N} \cdot \text{m}$ |
| Mounting Torque, M5 Main Terminal Screws | — | 2.5~3.5 | $\text{N} \cdot \text{m}$ |
| Module Weight (Typical) | — | 340 | Grams |
| Supply Voltage Protected by OC and SC ($V_D = 13.5 - 16.5\text{V}$, Inverter Part) | $V_{\text{CC(prot.)}}$ | 800 | Volts |
| Isolation Voltage (Main Terminal to Baseplate, AC 1 min.) | V_{iso} | 2500 | V_{rms} |

Control Sector

| | | | |
|--|------------------|----|-------|
| Supply Voltage (Applied between $V_{P1}-V_{PC}$, $V_{N1}-V_{NC}$) | V_D | 20 | Volts |
| Input Voltage (Applied between $C_{P1}-V_{PC}$, $C_{N1}-V_{NC}$) | V_{CIN} | 10 | Volts |
| Fault Output Supply Voltage (Applied between $F_{po}-V_{pc}$ and $F_{no}-V_{nc}$) | V_{FO} | 20 | Volts |
| Fault Output Current (Sink Current at F_{PO} , F_{NO} Terminal) | I_{FO} | 20 | mA |

IGBT Inverter Sector

| | | | |
|---|------------------------|------|---------|
| Collector-Emitter Voltage ($V_D = 15\text{V}$, $V_{\text{CIN}} = 5\text{V}$) | V_{CES} | 1200 | Volts |
| Collector Current, ($T_c = 25^\circ\text{C}$) | I_c | 100 | Amperes |
| Peak Collector Current, ($T_c = 25^\circ\text{C}$) | I_{CP} | 200 | Amperes |
| Supply Voltage (Applied between C1 - E2) | V_{CC} | 900 | Volts |
| Supply Voltage, Surge (Applied between C1 - E2) | $V_{\text{CC(surge)}}$ | 1000 | Volts |
| Collector Dissipation | P_c | 595 | Watts |

Electrical and Mechanical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

| Characteristics | Symbol | Test Conditions | Min. | Typ. | Max. | Units |
|---|-----------------------------|---|------|------|------|------------------|
| Control Sector | | | | | | |
| Over Current Trip Level Inverter Part | OC | $-20^\circ\text{C} \leq T \leq 125^\circ\text{C}$, $V_D = 15\text{V}$ | 145 | 230 | — | Amperes |
| Short Circuit Trip Level Inverter Part | SC | $-20^\circ\text{C} \leq T \leq 125^\circ\text{C}$, $V_D = 15\text{V}$ | 200 | 340 | — | Amperes |
| Over Current Delay Time | $t_{\text{off}}(\text{OC})$ | $V_D = 15\text{V}$ | — | 5 | — | μs |
| Over Temperature Protection | OT | Trip Level | 100 | 110 | 120 | $^\circ\text{C}$ |
| | OT_r | Reset Level | 85 | 95 | 105 | $^\circ\text{C}$ |
| Supply Circuit Under Voltage Protection | UV | Trip Level | 11.5 | 12.0 | 12.5 | Volts |
| | UV_r | Reset Level | — | 12.5 | — | Volts |
| Supply Voltage | V_D | Applied between $V_{P1}-V_{PC}$, $V_{N1}-V_{NC}$ | 13.5 | 15 | 16.5 | Volts |
| Circuit Current | I_D | $V_D = 15\text{V}$, $V_{\text{CIN}} = 5\text{V}$, $V_{N1}-V_{NC}$ | — | 19 | 26 | mA |
| | | $V_D = 15\text{V}$, $V_{\text{CIN}} = 5\text{V}$, $V_{\text{XP1}}-V_{\text{XPC}}$ | — | 19 | 26 | mA |
| Input ON Threshold Voltage | $V_{\text{th(on)}}$ | Applied between | 1.2 | 1.5 | 1.8 | Volts |
| Input OFF Threshold Voltage | $V_{\text{th(off)}}$ | $C_{P1}-V_{PC}$, $C_{N1}-V_{NC}$ | 1.7 | 2.0 | 2.3 | Volts |
| PWM Input Frequency | f_{PWM} | 3- ϕ Sinusoidal | — | 15 | 20 | kHz |
| Fault Output Current | $I_{\text{FO(H)}}$ | $V_D = 15\text{V}$, $V_{\text{FO}} = 15\text{V}$ | — | — | 0.01 | mA |
| | $I_{\text{FO(L)}}$ | $V_D = 15\text{V}$, $V_{\text{FO}} = 15\text{V}$ | — | 10 | 15 | mA |
| Minimum Fault Output Pulse Width | t_{FO} | $V_D = 15\text{V}$ | 1.0 | 1.8 | — | ms |
| SXR Terminal Output Voltage | V_{SXR} | $-20^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $R_{\text{in}} = 6.8 \text{ k}\Omega$ (S_{PR} , S_{NR}) | 4.5 | 5.1 | 5.6 | Volts |

Electrical and Mechanical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

| Characteristics | Symbol | Test Conditions | Min. | Typ. | Max. | Units |
|--------------------------------------|---------------|--|------|------|------|---------------|
| IGBT Inverter Sector | | | | | | |
| Collector Cutoff Current | I_{CES} | $V_{CE} = V_{CEX}, T_j = 25^\circ\text{C}$ | — | — | 1 | mA |
| | | $V_{CE} = V_{CEX}, T_j = 125^\circ\text{C}$ | — | — | 10 | mA |
| Emitter-Collector Voltage | V_{EC} | $-I_C = 100\text{A}, V_D = 15\text{V}, V_{CIN} = 5\text{V}$ | — | 2.5 | 3.5 | Volts |
| Collector-Emitter Saturation Voltage | $V_{CE(sat)}$ | $V_D = 15\text{V}, V_{CIN} = 0\text{V}, I_C = 100\text{A}$ | — | 2.3 | 3.2 | Volts |
| | | $V_D = 15\text{V}, V_{CIN} = 0\text{V}, I_C = 100\text{A},$ $T_j = 125^\circ\text{C}$ | — | 2.1 | 2.9 | Volts |
| Inductive Load Switching Times | t_{on} | | 0.5 | 1.4 | 2.5 | μs |
| | t_{rr} | $V_D = 15\text{V}, V_{CIN} = 0 \leftrightarrow 5\text{V}$ | — | 0.2 | 0.4 | μs |
| | $t_{C(on)}$ | $V_{CC} = 600\text{V}, I_C = 100\text{A}$ | — | 0.4 | 1.0 | μs |
| | t_{off} | $T_j = 125^\circ\text{C}$ | — | 2.5 | 3.5 | μs |
| | $t_{C(off)}$ | | — | 0.6 | 1.1 | μs |

Thermal Characteristics

| Characteristic | Symbol | Condition | Min. | Typ. | Max. | Units |
|-------------------------------------|----------------|---|------|------|-------|-----------------------|
| Junction to Case Thermal Resistance | $R_{th(j-c)Q}$ | Each IGBT | — | — | 0.21 | $^\circ\text{C/Watt}$ |
| | $R_{th(j-c)F}$ | Each FWDi | — | — | 0.35 | $^\circ\text{C/Watt}$ |
| Contact Thermal Resistance | $R_{th(c-f)}$ | Case to Fin Per Module, Thermal Grease Applied | — | — | 0.060 | $^\circ\text{C/Watt}$ |

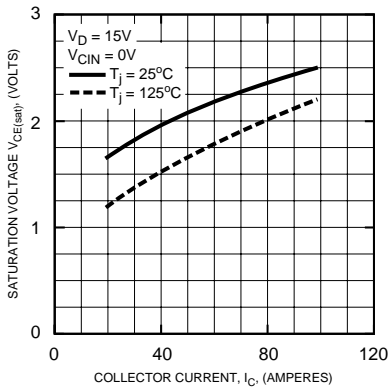
Recommended Conditions for Use

| Characteristic | Symbol | Condition | Value | Units |
|---------------------|----------------|--|--------------------|---------------|
| Supply Voltage | V_{CC} | Applied across C1-E2 Terminals | 0 ~ 800 | Volts |
| | V_D | Applied between $V_{P1}-V_{PC}, V_{N1}-V_{NC}$ | 15 ± 1.5 | Volts |
| Input ON Voltage | $V_{CIN(on)}$ | Applied between | 0 ~ 0.8 | Volts |
| Input OFF Voltage | $V_{CIN(off)}$ | $C_{P1}-V_{PC}, C_{N1}-V_{NC}$ | $4.0 \sim V_{SXR}$ | Volts |
| PWM Input Frequency | f_{PWM} | Using Application Circuit | 5 ~ 20 | kHz |
| Minimum Dead Time | t_{dead} | Input Signal | ≥ 3.5 | μs |

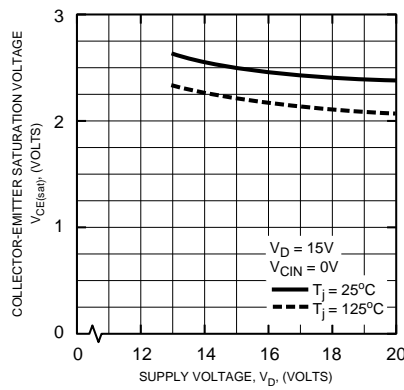
PM100DSA120

FLAT-BASE TYPE
INSULATED PACKAGE

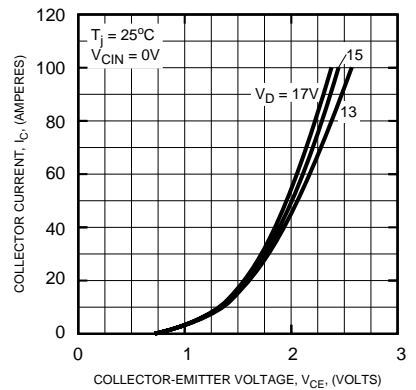
SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



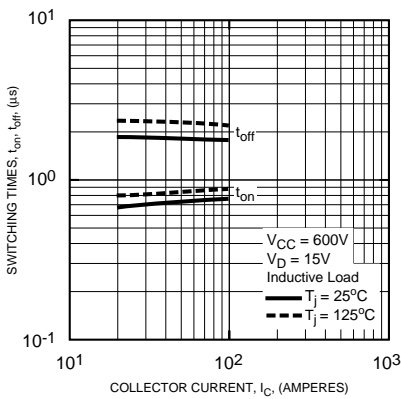
COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



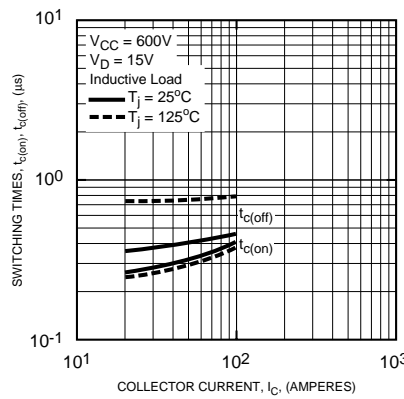
OUTPUT CHARACTERISTICS (TYPICAL)



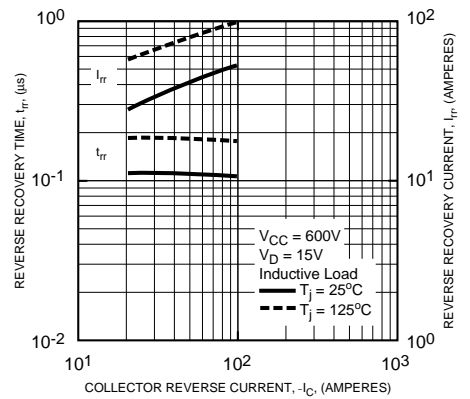
SWITCHING TIME VS. COLLECTOR CURRENT (TYPICAL)



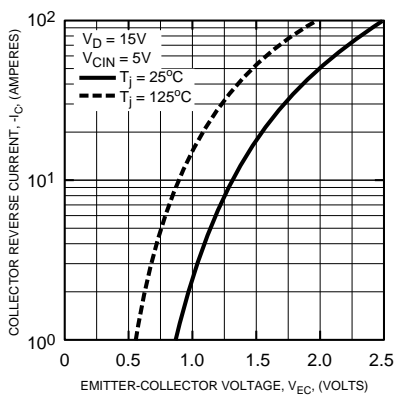
SWITCHING TIME VS. COLLECTOR CURRENT (TYPICAL)



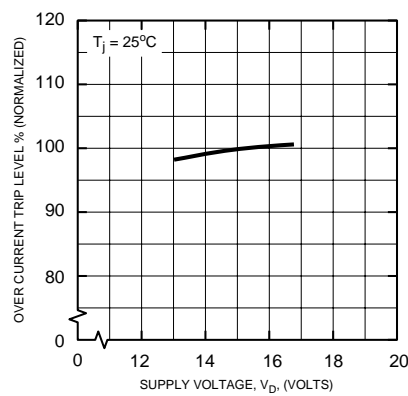
REVERSE RECOVERY CURRENT VS. COLLECTOR CURRENT (TYPICAL)



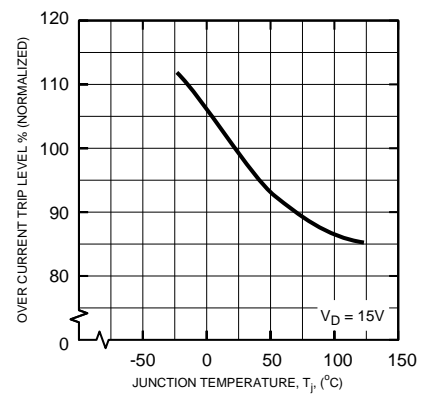
DIODE FORWARD CHARACTERISTICS



OVER CURRENT TRIP LEVEL VS. SUPPLY VOLTAGE (TYPICAL)



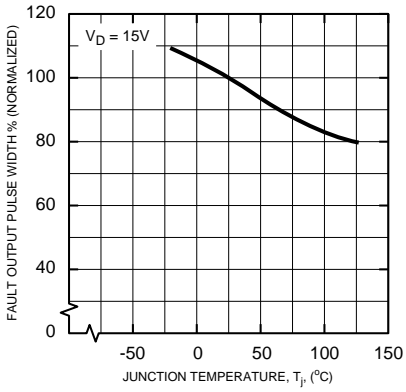
OVER CURRENT TRIP LEVEL TEMPERATURE DEPENDENCY (TYPICAL)



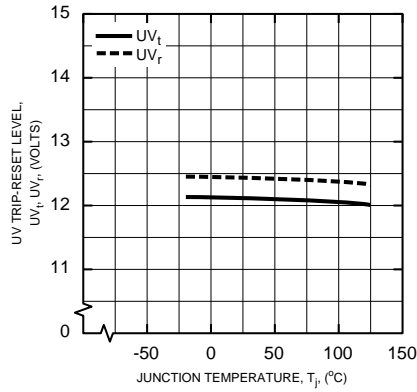
PM100DSA120

FLAT-BASE TYPE
INSULATED PACKAGE

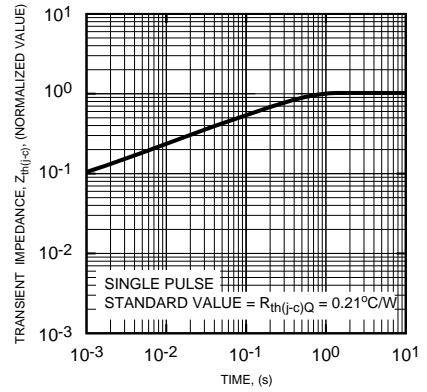
FAULT OUTPUT PULSE WIDTH VS. TEMPERATURE (TYPICAL)



CONTROL SUPPLY VOLTAGE TRIP-RESET LEVEL TEMPERATURE DEPENDENCY (TYPICAL)



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (Each IGBT)



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (Each FWDi)

